

Continental Device India Limited An ISO/TS 16949, ISO 9001 and ISO 14001 Certified Company





2N3903 / 2N3904

TO-92 Plastic Package For Lead Free Parts, Device Part # will be Prefixed with "T"

General Purpose Switching And Amplifier Applications

ABSOLUTE MAXIMUM RATINGS (T_a=25°C)

с в С

(·a					
DESCRIPTION	SYMBOL	VALUE			UNITS
Collector Emitter Voltage	V _{CEO}	40			V
Collector Base Voltage	V _{CBO}	60	V		
Emitter Base Voltage	V _{EBO}	6.0			V
Collector Current Continuous	I _C	200			mA
Power Dissipation at T _a =25 ^o C	P _D	625			mW
Derate Above 25ºC		5.0			mW/⁰C
Power Dissipation at T _c =25 ^o C	P _D	1.5			W
Derate Above 25°C		12			mW/⁰C
Operating and Storage Junction	тт	-55 to +1	50		°C
Temperature Range	•j, •stg	00.00			Ũ
THERMAL RESISTANCE					
Junction to Case	R _{th (j-c)}	83.3			°C/W
Junction to Ambient in free air	R _{th (j-a)}	200			°C/W
ELECTRICAL CHARACTERISTICS (T	a=25⁰C ur	nless specified otherwise)			
DESCRIPTION	SYMBOL	TEST CONDITION 2N3903 2N3904			UNITS
Collector Emitter Voltage	V _{CEO}	I _C =1mA, I _B =0	>40	>40	V
Collector Base Voltage	V _{CBO}	I _C =10μΑ. I _E =0	>60	>60	V
Emitter Base Voltage	V _{EBO}	I _E =10μΑ, I _C =0	>6.0	>6.0	V
Base Cut Off Current	I _{BL}	V _{CE} =30V, V _{EB} =3V < 50 < 50		nA	
Collector Cut Off Current	I _{CEX}	V_{CE} =30V, V_{EB} =3V	< 50	< 50	nA
DC Current Gain	*h _{FE}	$I_{C}=0.1$ mA, $V_{CE}=1$ V	>20	>40	
		I _C =1mA, V _{CE} =1V	>35	>70	
		I _C =10mA, V _{CE} =1V 50-150 10		100-300	
		I _C =50mA, V _{CE} =1V	>30	>60	
		$I_C=100mA$, $V_{CE}=1V$	>15	>30	
Collector Emitter Saturation Voltage	*V _{CE (sat)}	I _C =10mA, I _B =1mA < 0.2 < 0.2		V	
		I _C =50mA, I _B =5mA	< 0.3	< 0.3	V
Base Emitter Saturation Voltage	*V _{BE (sat)}	I _C =10mA, I _B =1mA	0.65 - 0.85	0.65 - 0.85	V
		I _C =50mA, I _B =5mA	< 0.95	< 0.95	V

*Pulse Condition: =300ms, Duty Cycle=2%

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NPN SILICON PLANAR EPITAXIAL SWITCHING TRANSISTORS



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ELECTRICAL CHARACTERISTICS (T_a=25°C unless specified otherwise)

SMALL SIGNAL CHARACTERISTICS

DESCRIPTION	SYMBOL	TEST CONDITION	NDITION 2N3903 2N3904 UN		UNITS
Transistors Frequency	f_T $I_C=10mA$, $V_{CE}=20V$, f=100MHz		>250	>300	MHz
Output Capacitance	C _{ob}	V _{CB} =5V, I _E =0, f=1MHz	< 4.0	<4.0	pF
Input Capacitance	C _{ib}	V_{EB} =0.5V, I_{C} =0, f=1MHz	< 8.0	< 8.0	pF
		ALL f=1kHz			
Small Signal Current Gain	h _{fe}	I _C =1mA, V _{CE} =10V	50 - 200	100 - 400	
Input Inpedence	h _{ie}	I _C =1mA, V _{CE} =10V	1.0 - 8.0	1.0 -10	kΩ
Voltage Feedback Ratio	h _{re}	I _C =1mA, V _{CE} =10V	0.1 - 5.0	0.5 - 8	x10 -4
Out put Adimttance	dimttance h _{oe} I _C =1mA, V _{CE} =10V 1.0 - 4		1.0 - 40	1.0 - 40	μmhos
Noise Figure	NF	I _C =100μA, V _{CE} =5V, f=1KHz, R _S =1KΩ	V, f=1KHz, < 6.0 < 5.0		dB
SWITCHING Time					
Delay time	t _d	V_{CC} =3V, V_{BE} =0.5V	< 35	< 35	ns
Rise time	t _r	I _C =10mA, I _{B1} =1mA < 35		< 35	ns
Storage time	ts	$V_{CC}=3V$, $I_{C}=10mA$	< 175	< 200	ns
Fall time	t _f	I _{B1} =1 _{B2} =1mA	< 50	< 50	ns

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DIM	MIN.	MAX.			
А	4.32	5.33			
В	4.45	5.20			
С	3.18	4.19			
D	0.41	0.55			
E	0.35	0.50			
F	5 DEG				
G	1.14	1.40			
Н	1.20	1.40			
K	12.70				
L	1.982	2.082			
М	1.03	1.20			

All dimensions are in mm





PIN CONFIGURATION 1. COLLECTOR

- 2. BASE
- 3. EMITTER

The TO-92 Package, Tape and Ammo Pack Drawings are correct as on the date of issue/revision of this Data Sheet. The currently valid dimensions and information, may please be confirmed from the TO-92 Drawing in the Packages and Packing Section of the Product Catalogue.

Packing Details

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
TO-92 Bulk	1K/polybag	200 gm/1K pcs	3" x 7.5" x 7.5"	5K	17" x 15" x 13.5"	80K	23 kgs
TO-92 T&A	2K/ammo box	645 gm/2K pcs	12.5" x 8" x 1.8"	2K	17" x 15" x 13.5"	32K	12.5 kgs

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Parting Line

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TO-92 Tape and Ammo Pack

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All	aimension	is are	IN	mm

		SPECIFICATION			NO			
IIEM	SYMBOL	MIN.	NOM.	MAX.	TOL.			
BODY WIDTH	A1	4.45		5.20	(NOTES		
BODY HEIGHT	A	4.32		5.33		1. Maximum alignment deviation between		
BODY THICKNESS	Т	3.18		4.19		leads will not to be greater than 0.2mm.		
PITCH OF COMPONENT	Р		12.7		± 1.0	2. Maximum non-cumulative variation		
*1FEED HOLE PITCH	Po		12.7		± 0.3	between tape feed holes shall not		
*2 FEED HOLE CENTRE TO	0.000		0.000000567			exceed 1 mm in 20 pitches.		
COMPONENT CENTRE	P2		6.35		± 0.4	3. Holddown tape will not exceed beyond		
DISTANCE BETWEEN OUTER	-		5.00		+ 0.6	the edge(s) of carrier tape and there		
LEADS	E.		5.08		- 0.2	shall be no exposure of adhesive.		
*3 COMPONENT ALIGNMENT SIDE VIEW	Δh		0	1.0		 There will be no more than three (3) 		
*4 COMPONENT ALIGNMENT FRONT VIEW	Δh1		0	1.3		consecutive missing components in a		
TAPE WIDTH	W		18		± 0.5	tape.		
HOLD-DOWN TAPE WIDTH	Wo		6		± 0.2	5. A tape trailer, having at least three feed		
HOLE POSITION	W1		9		+ 0.7	component in a tape.		
HOLD-DOWN TAPE POSITION	W2	0.0		0.7		6. Splices should not interfere with the		
LEAD WIRE CLINCH HEIGHT	Ho	V 00 200505	16	11012030	± 0.5	sprocket feed holes.		
COMPONENT HEIGHT	H1		20000	24.0				
LENGTH OF SNIPPED LEADS	L			11.0				
FEED HOLE DIAMETER	Do		4		± 0.2	DEMADKS		
*5 TOTAL TAPE THICKNESS	t			1.2		REMARKS		
LEAD - TO - LEAD DISTANCE	F1, F2	2.40		2.70	27.20	" Cumulative pitch error 1.0 mm/20 pitch		
STAND OFF	H2	0.45		1.45	- 0.1	*2 To be measured at bottom of clinch		
CLINCH HEIGHT	H3			3.0		*3 At top of body		
LEAD PARALLELISM	[C1 - C2]			0.22		*4 At top of body		
PULL - OUT FORCE	(p)	6N		100000000		*5 t1 0.3 – 0.6 mm		

Component Disposal Instructions

- 1. CDIL Semiconductor Devices are RoHS compliant, customers are requested to please dispose as per prevailing Environmental Legislation of their Country.
- 2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).

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Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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